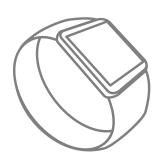
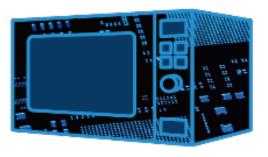
Microwave Oven

Solution Proposal by Toshiba



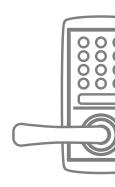






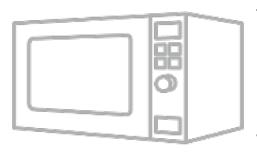




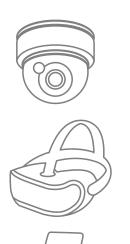








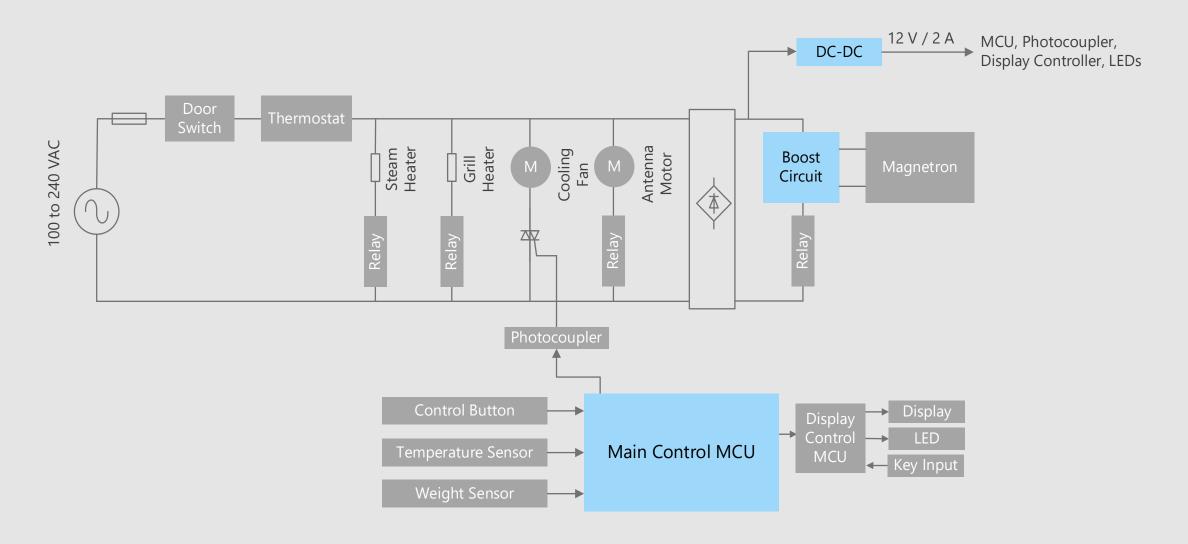
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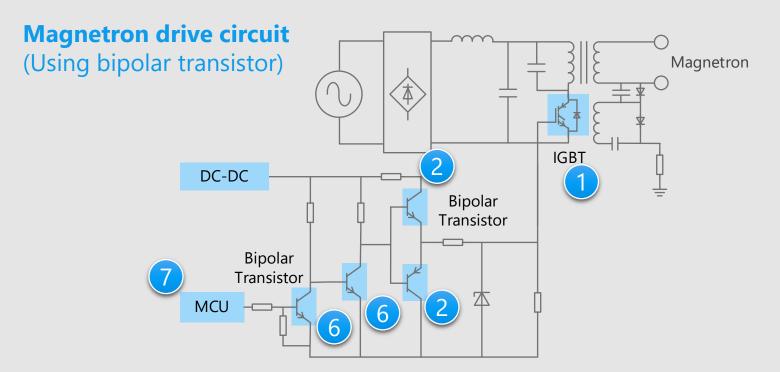
Block Diagram

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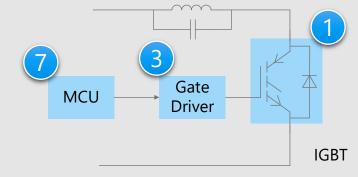
Microwave Oven Overall block diagram



Microwave Oven Details of magnetron drive circuit



Magnetron drive circuit (Using gate driver coupler)



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

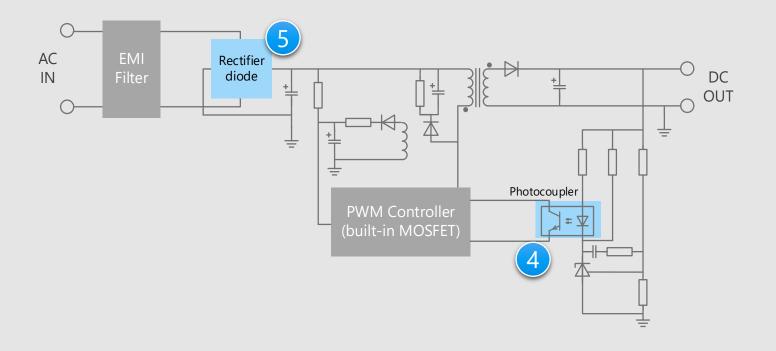
- Both high speed switching and low saturation voltage are required for IGBT.
- Small package products contribute to the reduction of circuit board area.
- Rail to Rail, low input current and low current consumption characteristics are required for gate driver to reduce power consumption.
- System control requires an MCU that can process data from various sensors at high speed.

Proposals from Toshiba

- High efficiency with high speed switching and low saturation voltage
 Discrete IGBT
- Contribute to loss reduction by high speed switching and high h_{FE}
 Bipolar transistor for IGBT gate drive
- High efficiency due to Rail to Rail characteristics
 IGBT gate driver coupler
- High voltage and high h_{FE}
 Bipolar transistor
- High efficient processing of multiple input and output data MCU

Microwave Oven Details of power supply circuit

Flyback type AC-DC converter



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

- Photocoupler with high current transfer ratio even in the low input current range contributes to higher power supply efficiency.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

High current transfer ratio and high temperature operation make easy to design.

Transistor output photocoupler

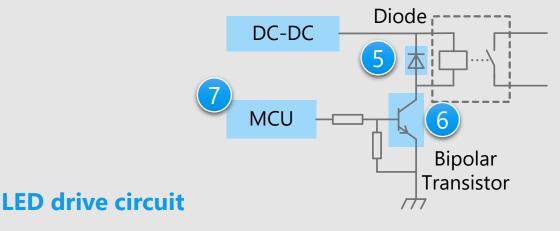
Small surface mount package suitable for high density mounting

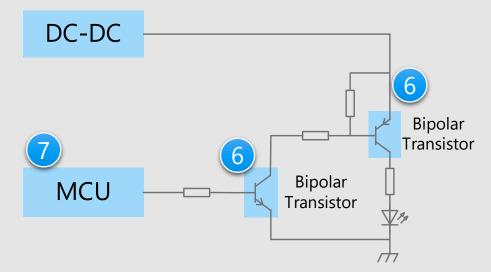
Rectifier diode



Microwave Oven Details of Relay / LED drive

Relay drive circuit





* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

- The use of a bipolar transistor with a low collector-emitter saturation voltage V_{CE(sat)} has an advantage in power utilization efficiency.
- Small package products contribute to the reduction of circuit board area.
- System control requires an MCU that can process data from various sensors at high speed.

Proposals from Toshiba

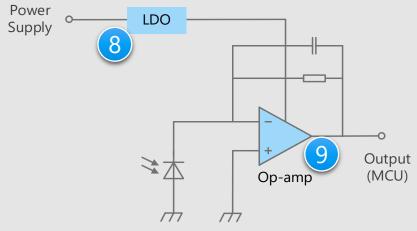
- Small surface mount package suitable for high density mounting Switching diode
- **Low V**_{CE(sat)}
 Bipolar transistor
- High efficient processing of multiple input and output data
 MCU



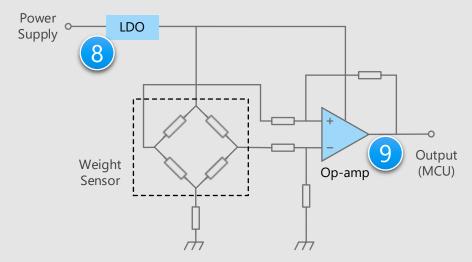


Microwave Oven Details of sensor input unit

Temperature sensor circuit



Weight sensor circuit



* Click on the numbers in the circuit diagram to jump to the detailed descriptions page

Criteria for device selection

- PSRR (Power Supply Rejection Ratio) of LDO regulator is an important parameter for sensor modules.
- The operational amplifier should be low current consumption or low noise device.
- Small package products contribute to the reduction of circuit board area.

Proposals from Toshiba

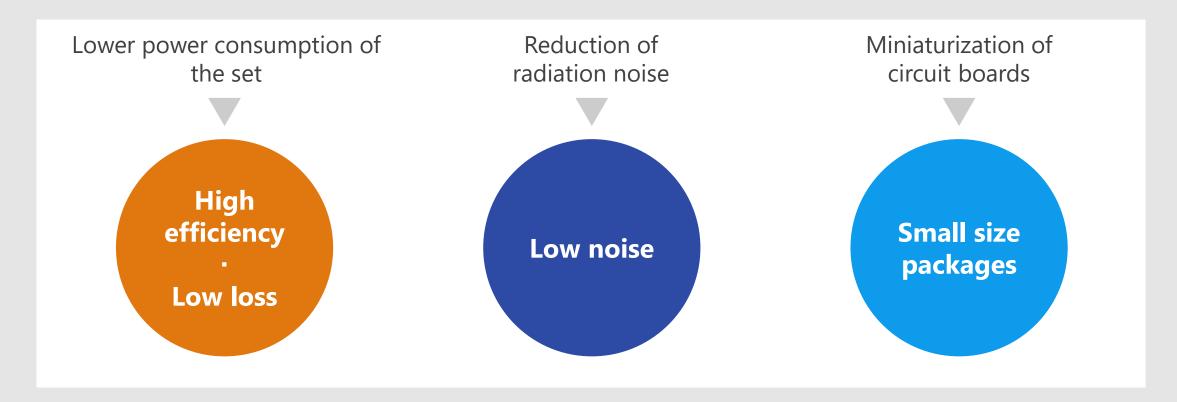
- Supply the power with low noise
 Small surface mount LDO regulator
- Amplification of detected very small signal with low noise
 - Low current consumption op-amp / Low noise op-amp



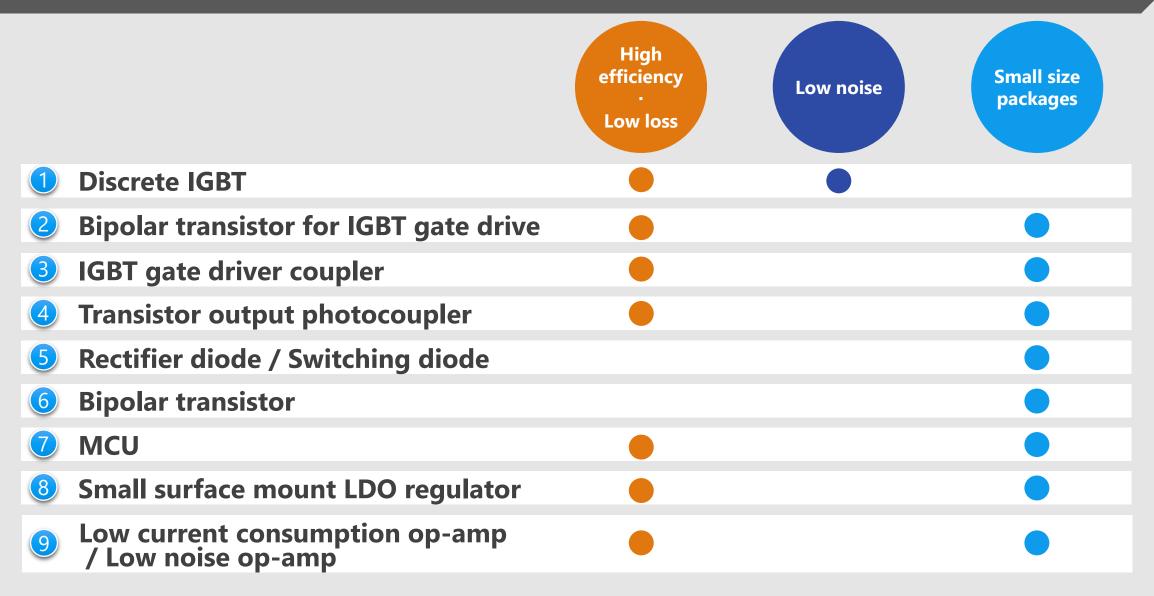


Device solutions to address customer needs

As described above, in the design of microwave oven, "Lower power consumption of the set", "Reduction of radiation noise" and "Miniaturization of circuit boards" are important factors. Toshiba's proposals are based on these three solutions perspectives.



Device solutions to address customer needs









High speed switching and low saturation voltage characteristics contribute to high efficiency.

High speed switching

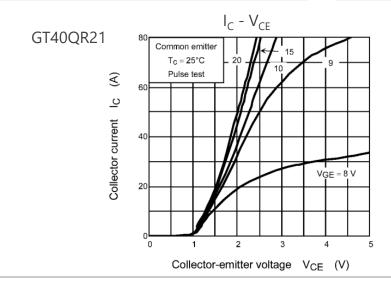
Reducing switching loss through high speed operation contributes to higher power supply efficiency.

2 Low saturation voltage

Saturation voltage is kept low while realizing high speed switching.

3 Enhancement type

Enhancement type is easy to design because no collector current flows when no gate voltage is applied.



Lineup				
Part number	GT40QR21	GT30J110SRA	GT30N135SRA	
Package	TO-3P(N)	TO-3P(N)	TO-247	
V _{CES} [V]	1200	1100	1350	
t _f (Typ.) [μs]	0.20 @I _C = 40 A	0.17 @I _C = 60 A	0.25 @I _C = 60 A	
V _{CE(sat)} (Typ.) [V]	1.9 @I _C = 40 A	2.15 @I _C = 60 A	2.15 @I _C = 60 A	







High speed switching characteristics and high h_{FE} performance enable the system to have higher frequencies and lower losses.

High speed switching operation

These transistors have high speed switching characteristic suitable for high frequency equipment.

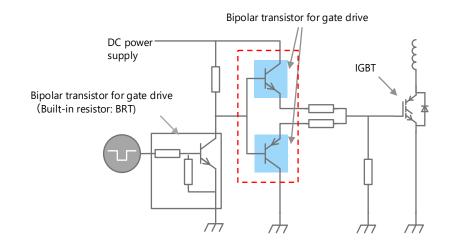
High DC current gain (h_{FE})

Maximum rating of collector current and DC current gain is improved for larger IGBT gate capacitance.

3 Small and thin package

Both PNP and NPN type are mounted on one small surface mount package to reduce mounting area.

Emitter terminals of PS-8 package is independent, so it is easy to divide the gate resistance ON/OFF.



Lineup				
Part number	HN4B101J	HN4B102J	TPCP8901	TPCP8902
Package	12	ΜV	PS	5-8
Internal structure (Top View)	5 4 PNP NPN 1 2 3		NF	7 6 5 N PNP
V _{CEO} [V] (PNP / NPN)	-30 / 30	-30 / 30	-50 / 50	-30 / 30
I _{CP} [A] (PNP / NPN)	-5 / 5	-8 / 8	-5 / 5	-8 / 8







Rail to Rail output enables the system to operate stably and reduce conduction losses.

Rail to Rail output

These driver couplers generate a full swing voltage output signal and contribute to low power consumption.

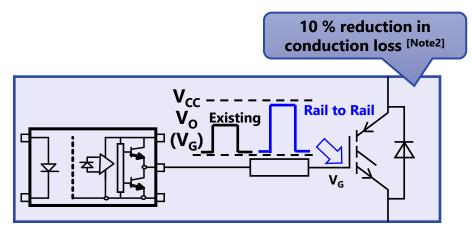
Small package

These driver couplers are 50 % smaller than the 8-pin DIP package [Note1] and meet the reinforced insulation class requirements of international safety standards.

[Note1] Comparison with Toshiba products

Operational ambient temperature range 125 °C

These driver couplers are designed to operate under severe ambient temperature conditions.



[Note2] Comparisor	with	conventional	Toshiba	products
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Lineup						
Part number	TLP5771H	TLP5772H	TLP5774H	TLP5751H	TLP5752H	TLP5754H
Package	SC	06L		SO6L SO6L		
I _{OP} (Max) [A]	±1	±2.5	±4	±1	±2.5	±4
t _{pHL} /t _{pLH} (Max) [ns]		150		150		
BV _s [Vrms]		5000 5000				
T _{opr} [°C]		-40 to 125			-40 to 125	
V _{CC} [V]	_{CC} [V] 10 to 30 15 to 30					
I _{FLH} (Max) [mA]		2		4		







The built-in various protective functions make it easy to design the gate drive circuit.

Protective Functions

TLP5231 delivers various built-in functions [Note], including an overcurrent detection by monitoring collector voltage.

[Note] Gate signal soft turn off, fault feedback function

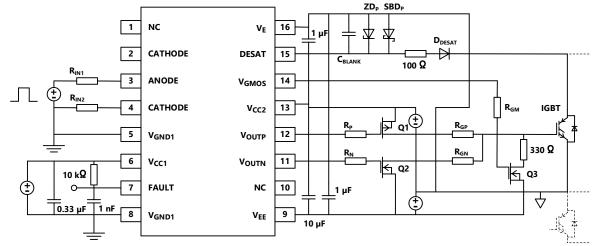
Rail to Rail output

TLP5231 generates a full swing voltage output signal and contributes to low power consumption.

Operational ambient temperature range 110 °C

TLP5231 is designed to operate under severe ambient temperature conditions.

Example Application Circuit



Lineup	
Part number	TLP5231
Package	SO16L
I _{OP} (Max) [A]	±2.5
t _{pHL} /t _{pLH} (Max) [ns]	300
BV _s [Vrms]	5000
T _{opr} [°C]	-40 to 110
V _{CC2} – V _{EE} [V]	21.5 to 30
I _{FHL} (Max) [mA]	3.5

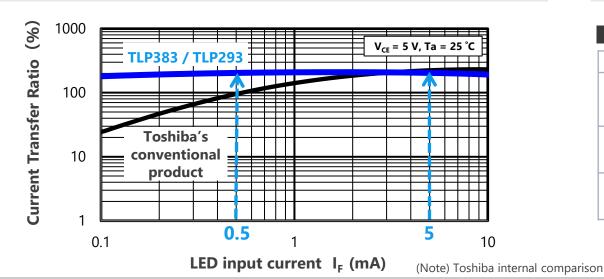




High CTR (Current Transfer Ratio) is realized even in low input current range ($I_F = 0.5 \text{ mA}$).

High current transfer ratio

The TLP383 and TLP293 are high-isolation photocouplers that optically couple a phototransistor and high output infrared LED. Compared to Toshiba's conventional product (TLP385), higher CTR (Current Transfer Ratio) in low input current range ($@I_F = 0.5$ mA) is realized.



High temperature operation

The TLP383, TLP293 and TLP385 are designed to operate even under severe ambient temperature conditions.

Lineup			
Part number	TLP383	TLP293	TLP385
Package	4pin SO6L	SO4	4pin SO6L
BV _S [Vrms]	5000	3750	5000
T _{opr} [°C]	-55 to 125	-55 to 125	-55 to 110

Sectifier diode / Switching diode







Value provided

Various products are provided, mainly small package that is suitable for high density assembly.

Surface mount / Small package

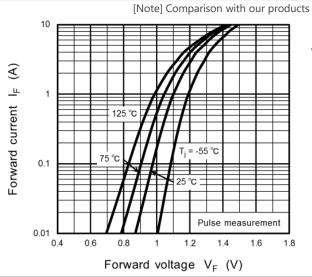
Adopting M-FLATTM package which is lower in height compared to the existing lead type [Note] contributes to effective use of space inside equipment.

Wide product lineup (1)

Reverse voltage: 200 to 1000 V Average forward current: 0.5 to 3 A Suitable product can be selected according to requirements.

Wide product lineup (2)

We also offer a lineup of low voltage, small package diodes to protect the inductive loads of mechanical relays.



 CMG06A forward characteristic

Lineup		
Part number	CMG06A	1SS352
Package	M-FLAT™	USC
I _{F(AV)} [A]	1	0.1 (for I _O)
V _{RRM} [V]	600	80 (for V _R)





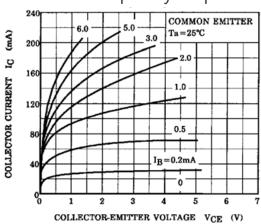


Various products are provided for radio frequency applications, power supply applications and other.

High voltage

High voltage allows for large loads and instantaneous voltage changes.

High voltage and high current, suitable for low frequency amplification



(TMBT3904: Max) High breakdown voltage: $V_{CEO} = 50 \text{ V}$ Large current: $I_C = 200 \text{ mA}$

2 Large current

It covers a wide range of applications, from high frequency applications to power supply applications, and is particularly suitable for applications requiring current capacity.

Lineup			
Part number	TMBT3906	TMBT3904	2SC4116
Package	SOT23	SOT23	USM 🗼
V _{CEO} [V]	-50	50	50
I _C [mA]	-200	200	150
V _{CE(sat)} (Max) [V]	-0.25	0.2	0.25
h _{FE}	100 to 300	100 to 300	70 to 700
Polarity	PNP	NPN	NPN







System control at low power consumption by multi-channel timers and AD Converters (ADCs).

Built-in Arm® Cortex®-M3 CPU core

TMPM383FSUG implements Arm Cortex-M3 core. Various development tool and their partners allow users many options.

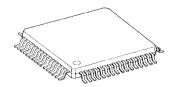
2 System cost down and development efficiency improvement

Built-in multi-channel ADCs and timers enable efficient monitoring and motoring of various parts of the system. Toshiba's original NANOFLASH™ is possible to rewrite at high speed. It reduces user software development time.

Small size package and low power consumption

TMPM383FSUG supports low power consumption library and stand by function. These contribute to reduce low power consumption. The package is small LQFP64.

TMPM383FSUG



Package: LQFP64-P-1010-0.50E

Lineup

Part number	TMPM383FSUG
Maximum operation frequency	40 MHz
Instruction ROM	64 KB
RAM	8 KB
Arm [®] Thumb [®] -2 Instruction set	Available
Timer	16bit x 8ch
I ² C	1ch
AD Converter	10ch (12bit)







Wide lineup from general purpose type to WCSP (Wafer Level Chip Size Package) type are provided. Contribute to realize a stable power supply.

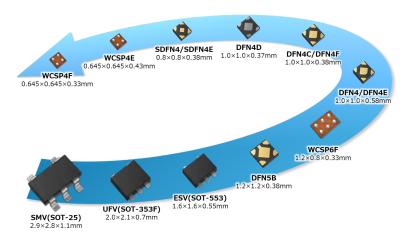
Low dropout voltage

Low dropout voltage characteristic has been realized by the originally developed process. High PSRR Low output noise voltage

Many product series that realize both high PSRR (Power Supply Rejection Ratio) and low output noise voltage characteristics are provided. They are suitable for stable power supply for analog circuit. 3 Low current consumption

 $0.34~\mu A$ of $I_{B(ON)}$ is realized by utilizing CMOS process and unique circuit technology. (TCR3U Series)

Rich package lineup



Lineup										
Part number	TCR15AG Series	TCR8BM Series	TCR5FM Series	TCR5RG Series	TCR3RM Series	TCR3U Series	TCR3LM Series	TCR3D Series	TCR3EM Series	TCR1HF Series
Features	volt	ropout age PSRR		Low noise			Low current Standard type		36 V Input voltage	
I _{OUT} (Max) [A]	1.5	0.8	0.	0.5			0.3			0.15
PSRR (Typ.) [dB] @f = 1 kHz	95	98	91	100	100	70	-	72	68	70
I _B (Typ.) [μΑ]	25	20	10	7	7	0.34	1	86	35	170



Low current consumption op-amp / Low noise op-amp tc755102F / Tc75567TU







Value provided

The lineup includes a low current consumption type that contributes to reducing power consumption and a low noise type that brings out performance of the sensor.

Low voltage operation

We have a lineup of low power supply voltage-driven operational amplifiers using CMOS process.

Low current consumption (TC75S102F) I_{DD} = 0.27 [μA] (Typ.)

CMOS processes have been used to achieve lower current consumption. This contributes to lower power consumption of various equipment.

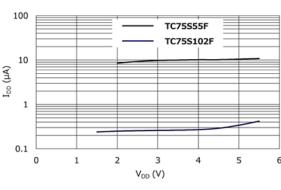
Low noise (TC75S67TU)

V_{NI} = 6.0 [nV/√Hz] (Typ.) @f = 1 kHz

This CMOS operational amplifier can amplify minute signals detected by various sensors [Note] with very low noises. By optimizing the process, the equivalent input noise voltage has been reduced.

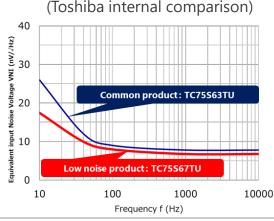
TC75S102F

Current Consumption Characteristic (Toshiba internal comparison)





Noise Characteristic (Toshiba internal comparison)



[Note] Sensor types: vibration, shock, acceleration, pressure, infrared, temperature, etc.

Lineup		
Part number	TC75S102F	TC75S67TU
Package	SMV	UFV
V _{DD} - V _{SS} [V]	1.5 to 5.5	2.2 to 5.5
V _{IO} (Max) [mV]	1.3	3
CMV _{IN} (Max) [V]	V_{DD}	1.4 (@V _{DD} = 2.5 V)
I _{DD} (Typ. / Max) [μA]	0.27 / 0.46 (@V _{DD} = 1.5 V)	430 / 700 (@V _{DD} = 2.5 V)
V _{NI} (Typ.) [nV/√Hz] @f = 1 kHz	-	6

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